## NSN 5962-00-419-0278

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View Online at https://aerobasegroup.com/nsn/5962-00-419-0278

view Offiline at https://aerobasegroup.com/nish/0302-00-413-0270
Body Length:
Between 0.240 inches and 0.260 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.030 inches and 0.070 inches
Maximum Power Dissipation Rating:
450.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and programmable and programmed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Current-mode logic
Input Circuit Pattern:
8 input
Case Outline Source And Designator:
T0-86 joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
25.0 volts power source
Time Rating Per Chacteristic:
10.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Diode matrix
Test Data Document:
94990-12-37300b drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
14 flat leads
Shelf Life:

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

N/a

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